Millimeter-wave Beamforming IC and Antenna Modules with Bi-directional Transceiver Architecture

OSHIMA Naoki, HORI Shinichi, PANG Jian, SHIRANE Atsushi, OKADA Kenichi, KUNIHIRO Kazuaki

Abstract

Millimeter-wave (mmW) communication is expected to provide high-speed data services in 5G (fifth-generation mobile communication system). Phased array antennas are essential for overcoming large path loss and less diffraction, and for utilizing mmW effectively. A low-cost and compact mmW phased array module integrating antennas and beamformer integration circuits (BFICs) is a key device for widespread use of mmW in 5G. This paper describes mmW phased-array transceiver implementation techniques including BFIC and antenna module. The BFIC employs area-efficient neutralized bi-directional technique which shares the circuit chain between TX and RX modes. Using the developed 28GHz BF ICs with 65-nm CMOS technology, the two types of phased array antenna modules, i.e., antenna on board (AoB) and antenna in package (AiP), are developed. A 64-element dual-polarized 28 GHz phased array AoB achieves a peak EIRP of 52.2 dBm and EVM of 3.2% at 64QAM for 5G NR. A 4-element phased array AiP with wafer level package (WLP) has an extremely low profile and high scalability applicable to various types of 5G devices.

Keywords

Millimeter-wave, 5G, Phased Array, CMOS, Antenna in Package, Wafer Level Package

1. Introduction

The 5th generation mobile communication system (5G) aspires to achieve high speed communication at or above 10 Gbit/s, which is 10 times or even faster than the previous generation technology, in order to support the spread of 4K/8K high-definition video transmission and new services, such as VR/AR. To realize it, 5G makes use of the mmW band (30 to 300 GHz) that provides a greater signal bandwidth. However, mmW have characteristics that make them difficult to use for mobile communications. For example, they not only attenuate significantly but also have less diffraction, which make them less likely to go around corners to reach areas shadowed by buildings. Beamforming is an effective technology for in compensating for such characteristics. It is a technology to form a concentrated beam toward a certain direction by controlling the spread of radio waves into the space. By concentrating the power toward the direction of the terminal device with which a communication link should be established, the communication range can be extended. It is also possible to apply this technology to spatially multiplex wireless signal transmission to improve frequency utilization efficiency and increase communication capacity. The phased-array technology is used as a means to introduce beamforming to mmW band wireless communication¹⁾.

This paper describes the basic configuration of mmW phased array antennas and their implementation techniques including beamforming integrated circuits (ICs) and module.

2. Phased-array Transceiver Architecture

When using mmW for wireless communication, the primary task is to ensure a sufficiently large communication range. The higher the carrier frequency, the greater the free space path loss (FSPL). Therefore, in the mmW band, a sufficient link margin cannot be established if, like in the microwave band, nondirectional antennas are used for communication. This produces the need to extend the communication range by beamforming, enabled by the above-mentioned phased-array technology.

The transceiver used a phased-array antenna to realize wireless communication with beamforming. Although phased arrays can be either active or passive, amplifier

Millimeter-wave Beamforming IC and Antenna Modules with Bi-directional Transceiver Architecture



Fig. 1 Phased-array transceiver configuration.

equipped active phased-array antennas (APAAs) are widely used in 5G base stations and in 5G terminal devices. Active ones are of either analog type or digital type²⁾. The analog type is normally chosen because, as the mmW band signal processing requires the handling of signal in a bandwidth as wide as several hundreds of MHz, the choice of digital type will result in large power consumption by the A-D and D-A converters, as well as the need for enormous computation in digital signal processing.

Fig. 1 shows an example of analog type phased-array transceiver. Each antenna element has its own beamforming IC (BFIC) for the control of phase and amplitude. Components like the power amplifier and the low nose amplifier are built into the beamformer. A BFIC for mmW band communication for 5G integrates beamformers for 4 to 32 antenna elements depending on the purpose. While Fig. 1 assumes the use of RF phase shift method, there are reports of choosing LO or IF shift method instead, and the boundary with the modulation-demodulation circuit varies depending on the choice $^{3)4)}$. As to the question of to what extent a phased-array transceiver should include functions of the PHY and MAC layer, the situation varies from case to case among terminal device applications and base station applications, resulting in a wide variety of implementation styles. Each antenna element is connected to a beamformer to enable control of the beam pattern.

3. BFIC and Module Design

In the developed BFIC, the occupied on-chip area for each beamformer is reduced to half by the bi-directional technique⁴⁾. Each beamformer in this work consists of a bi-directional gain amplifier, a bi-directional active vector-summing phase shifter, and a power amplifier (PA)– low noise amplifier (LNA) as shown in **Fig. 2**. A schematic diagram of the bi-directional gain amplifier is shown in **Fig. 3**. The neutralized bi-directional core contains two differential pairs in the cross-coupling connection. The



Fig. 2 Block diagram of BFIC.



Fig. 3 Circuit diagram of bi-directional amplifier.

mode selection of the core is realized by switching the tail transistors M3 and M6. Fig. 3 (a) and (b) further explain the TX- and RX-mode operation of the core. By selecting the same transistor size among M1, M2, M4, and M5, the gate-drain capacitance neutralization could be maintained in both operating modes. Improved amplifier gain and reverse isolation are achieved. In addition, the transmission line (TL)-based passive matching components for the gain amplifier are shared between the TX mode and the RX mode in order to minimize the required chip area. At mmW frequencies, the required matching conditions for the proposed core will not change dramatically during the mode switching. Therefore, same TLs realize low-loss matching in both the TX mode and the RX mode. As a result, a high-performance and area-efficient bidirectional amplifier could be realized.

In an APAA, a number of antenna elements arranged at the pitch of about one-half of the wavelength must be fed signals from a BFIC. Since, in the mmW band, the short wavelength increases losses produced by wiring, BFICs and antenna elements must be placed close to one another as attempts are made to realize a compact, highly integrated module. An APAA module for use at wireless base stations normally has from ten and several to several tens of BFIC to control from 64 to 512 antenna elements. As shown in **Fig. 4**, the implementation style is largely classified into an antenna on board (AoB) and an antenna in package (AiP).

In the case of AoB, antenna elements are mounted on one side of the printed circuit board (PCB) and BFICs on the other side. As the primary advantage, the cost is low because a general-purpose PCB is used. In addition, it is easy to connect a heat sink immediately to the back of the BFIC chips, which are heat generators. This is also a great advantage for wireless base station applications that are prone to the problem of large heat output.

In the case of AiP, antennas are formed within a semiconductor IC package before it is placed on the PCB. AiP has the advantage of fined design rules and high manufacturing accuracy because advanced packaging technology is used. AiP is mostly chosen for the implementation of a relatively small array with 4 to 32 antenna elements. When it is applied to implement a larger array for use at base stations, a tile-like arrangement must be chosen as in the case of the example shown in Fig. 4 (b). High scalability and ease of testing are found to be advantages.

Whether AiP or AoB should be selected depending on the form of phased array equipment in which it is mounted.

4. Implementation and Measurements

A micrograph and a block diagram of the 28-GHz beamformer IC are shown in **Fig. 5**. Mature 65-nm CMOS technology was utilized, and the chip size was 4 mm \times 4 mm. The IC includes 4-channel H-pol. And



Fig. 4 Implementation styles of front-end modules.

4-channel V-pol. transceivers to support dual-polarized MIMO. The element transceiver implements the bi-directional architecture of a frontend amplifier, a variable gain amplifier, and a phase sifter for a compact chip size. The AoB and AiP type phased array antenna modules have been developed using the 28 GHz BFICs as follows.

Fig. 6 shows the AoB type phased-array module. Antenna elements form an array at the pitch of 6 mm, which corresponds to 0.56λ , where λ is the free space wavelength for 28 GHz, and the area size of the 16×4 two-dimensional array antenna module is about



Fig. 5 28 GHz band 8-element BFIC.



Fig. 6 AoB type APAA module.

3 cm×10 cm. For reducing losses, the wiring between antenna elements and BFICs are designed to be the shortest because a set of four antenna elements is made to connect with one BFIC (as in Fig. 2). The BFICs used for the AoB are fabricated with Fan-in wafer level package (WLP) technology to minimize the implementation size and loss. In over-the-air measurement, a 64-element dual-polarized phased-array module achieves 52.2-dBm saturated effective isotropic radiated power (EIRP). The measured DP-MIMO EVMs are 3.4% with standard-compliant DP-MIMO signals in 256-QAM. The specifics of these BFIC and AoB were reported in Reference 4).

The AiP has 2×2 dual-polarized phased array antennas using chip-last fan-out WLP technology. The size of the AiP is 13 mm × 13 mm × 0.47 mm. 2×2 square patch antennas are formed on the top layer of the RDL. The antenna pitch is 7 mm (0.65λ) (**Fig. 7**). The four AiPs were mounted on a PCB to form a 8×2 phased array antenna module as shown in **Fig. 8**. Here, the AiP is designed to be scalable so that the antenna spacing between the adjacent AiPs is kept at 0.65 λ .

The OTA measurements were conducted for the fabricated AiP and the phased array module. The AiP was tested in TX mode in a far-field using a vector network analyzer (VNA) and a standard gain horn antenna as a



Fig. 7 2×2 phased array AiP.



Fig. 8 8×2 AiP type APAA module.

receiver at a distance of 1 m. The beamformer ICs were controlled with FPGA via serial peripheral interface (SPI).



Fig. 9 Measured EIRP of developed 8×2 phased array module.



Fig. 10 Measured azimuth beam patterns of the 8×2 phased array module.



Fig. 11 Azimuth beam patterns and cross-polarization isolation of the 8×2 phased array module at a beam angle of 0° and 10°.

Millimeter-wave Beamforming IC and Antenna Modules with Bi-directional Transceiver Architecture

The overall V-pol. EIRP increases along an ideal slope of 6 dB/octave as the number of activated antenna elements increases as shown in **Fig. 9**, verifying the scalability of the developed AiP. When the 16 antenna elements, i.e., four AiPs, are activated, the peak EIRP reaches 40.5 dBm per polarization.

Fig. 10 shows the beam patterns of 8×2 antennas with scan resolution of 1-degree. The 3 dB beamwidth is +/- 40° as well as that of the single antenna. The side lobes are lower than -13 dB. Fig. 11 compares the measured and ideal beam pattern at direction angles of 0° and 10°, respectively. The cross-pol. isolations achieve over 25 dB. It's due to the antenna configuration and the manufacturing precision of AiPs.

5. Conclusion

This paper described mmW phased-array transceivers used in 5G focusing mainly on IC/module implementation techniques. In the BFIC, area-efficient neutralized bi-directional techniques were used for sharing the circuit chain between TX and RX modes. The two types of antenna modules, AoB and AiP, were developed using the BFICs. We demonstrated a dual-polarized 28-GHz 64-element phased array AoB and a 4-element scalable AiP. These BFIC and phased array module are key technologies for low-cost and compact mmW radio unis in 5G and beyond.

6. Acknowledgement

This work was partially supported by the Ministry of Internal Affairs and Communications in Japan (JPJ000254).

References

- 1) NEC: Beyond5G White Paper Technical Edition, March 2022 (Japanese)
 - https://jpn.nec.com/nsp/5g/beyond5g/pdf/NEC_B5G_ WhitePaper_technology.pdf
- 2) KUNIHIEO Kazuaki, OKADA Kenichi: Millimeter-wave CMOS Circuit Technology for 5G, The Journal of The Institute of Electronics, Information and Communication Engineers, Vol.101, No.11, pp.1123-1129, November 2018 (Japanese)
- 3) J. Pang, et al.: A 28-GHz CMOS Phased-Array Transceiver Based on LO Phase-Shifting Architecture With Gain Invariant Phase Tuning for 5G New Radio, IEEE Journal of Solid-State Circuits, Vol.54, No.5, pp.1228-1242, May 2019
- https://ieeexplore.ieee.org/document/8662773
- 4) J. Pang, et al.: A CMOS Dual-Polarized Phased-Array Beamformer Utilizing Cross-Polarization Leakage Cancellation for 5G MIMO Systems, IEEE Journal of Solid-State Circuits, Vol.56, No.4, pp.1310-1326, April 2021 https://ieeexplore.ieee.org/document/9316256

Copyright(C)2022 IEICE

K. Okada, J. Pang, A. Shirane, N. Oshima, K. Kunihiro: Millimeter-wave Phased-array Transceiver for 5G and Beyond, Journal of IEICE, Vol. 105, No.8, pp.706-712, August 2022

Copyright(C)2022 APMC

N. Oshima, S. Hori, J. Pang, A. Shirane, K. Okada, K. Kunihiro: A Low-Profile, Scalable 28-GHz Phased Array Antenna in Fan-Out Wafer-Level Package for 5G Communication, 2022 Asia-Pacific Microwave Conference (APMC), pp.359-361, December 2022

Authors' Profiles

OSHIMA Naoki

Professional Global Mobile Solution Department

HORI Shinichi

Professional Wireless Access Development Department

PANG Jian

Specially Appointed Associate Professor Tokyo Institute of Technology

SHIRANE Atsushi

Associate Professor Tokyo Institute of Technology

OKADA Kenichi

Professor Tokyo Institute of Technology

KUNIHIEO Kazuaki

Senior Professional Wireless Access Development Department

Information about the NEC Technical Journal

Thank you for reading the paper.

If you are interested in the NEC Technical Journal, you can also read other papers on our website.

Link to NEC Technical Journal website



Vol.17 No.1 Special Issue on Open Network Technologies

- Network Technologies and Advanced Solutions at the Heart of an Open and Green Society

Remarks for Special Issue on Open Network Technologies NEC's Technological Developments and Solutions for Open Networks

Papers for Special Issue

Open RAN and Supporting Virtualization Technologies

Innovations Brought by Open RAN Reducing Energy Consumption in Mobile Networks Self-configuring Smart Surfaces Nuberu: Reliable RAN Virtualization in Shared Platforms vrAIn: Deep Learning based Orchestration for Computing and Radio Resources in vRANs

Wireless Technologies for 5G/Beyond 5G

NEC's Energy Efficient Technologies Development for 5G and Beyond Base Stations toward Green Society Millimeter-wave Beamforming IC and Antenna Modules with Bi-directional Transceiver Architecture Radio-over-Fiber Systems with 1-bit Outphasing Modulation for 5G/6G Indoor Wireless Communication 28 GHz Multi-User Massive Distributed-MIMO with Spatial Division Multiplexing 28 GHz Over-the-Air Measurements Using an OTFS Multi-User Distributed MIMO System Comprehensive Digital Predistortion for improving Nonlinear Affection and Transceivers Calibration to Maximize Spatial Multiplexing Performance in Massive MIMO with Sub6 GHz Band Active Antenna System Black-Box Doherty Amplifier Design Method Without using Transistor Models 39 GHz 256 Element Hybrid Beam-forming Massive MIMO for 8 Multi-users Multiplexing

Initiatives in Open APN (Open Optical/All Optical)

NEC's Approach to APN Realization — Towards the Creation of Open Optical Networks NEC's Approach to APN Realization — Features of APN Devices (WX Series) NEC's Approach to APN Realization — Field Trials Wavelength Conversion Technology Using Laser Sources with Silicon Photonics for All Photonics Network Optical Device Technology Supporting NEC Open Networks — Optical Transmission Technology for 800G and Beyond

Initiatives in Core & Value Networks

Technologies Supporting Data Plane Control for a Carbon-Neutral Society NEC's Network Slicing Supports People's Lives in the 5G Era Application-Aware ICT Control Technology to Support DX Promotion with Active Use of Beyond 5G, IoT, and AI Using Public Cloud for 5G Core Networks for Telecom Operators

Enhancing Network Services through Initiatives in Network Automation and Security NEC's Approach to Full Automation of Network Operations in OSS

Autonomous Network Operation Based on User Requirements and Security Response Initiatives Enhancing Information and Communications Networks Safety through Security Transparency Assurance Technology Enhancing Supply Chain Management for Network Equipment and Its Operation

Network Utilization Solutions and Supporting Technologies

Positioning Solutions for Communication Service Providers The Key to Unlocking the Full Potential of 5G with the Traffic Management Solution (TMS) Introducing the UNIVERGE RV1200, All-in-one Integrated Compact Base Station, and Managed Services for Private 5G Vertical Services Leveraging Private 5G to Support Industrial DX Integrated Solution Combining Private 5G and LAN/RAN

Global 5G xHaul Transport Solutions xHaul Solution Suite for Advanced Transport Networks

xHaul Transport Automation Services xHaul Transport Automation Solutions Fixed Wireless Transport Technologies in the 5G and Beyond 5G Eras SDN/Automation for Beyond 5G OAM Mode-Multiplexing Transmission System for High-Efficiency and High-Capacity Wireless Transmission

Toward Beyond 5G/6G

NEC's Vision and Initiatives towards the Beyond 5G Era

NEC Information

2022 C&C Prize Ceremony



Vol.17 No.1 September 2023

